

CR05AM-16A

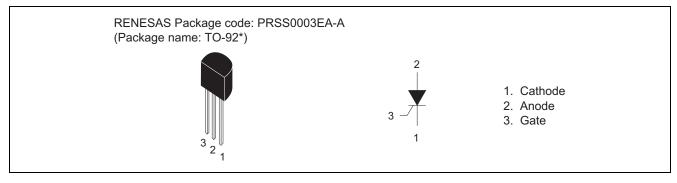
Thyristor

Low Power Use

R07DS0988EJ0100
Rev.1.00
Dec 05, 2012

Features

Outline



Applications

Leakage protector, timer, and gas igniter

Maximum Ratings

Parameter	Symbol	Voltage class	Unit	
Farameter	Symbol	16	Oill	
Repetitive peak reverse voltage	V_{RRM}	800	V	
Non-repetitive peak reverse voltage	V_{RSM}	960	V	
DC reverse voltage	$V_{R(DC)}$	640	V	
Repetitive peak off-state voltage Note1	V_{DRM}	800	V	
Non-repetitive peak off-state voltage Note1	V_{DSM}	960	V	
DC off-state voltage Note1	$V_{D(DC)}$	640	V	

Notes: 1. With gate to cathode resistance R_{GK} = 1 $k\Omega$

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T(RMS)}	0.47	Α	
Average on-state current	I _{T(AV)}	0.3	А	Commercial frequency, sine half wave 180° conduction, Ta = 62°C
Surge on-state current	I _{TSM}	10	А	60 Hz sine half wave, 1 full cycle, peak value, non-repetitive
I ² t for fusing	l ² t	0.4	A ² s	Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current
Peak gate power dissipation	P _{GM}	0.5	W	
Average gate power dissipation	P _{G(AV)}	0.1	W	
Peak gate forward voltage	V_{FGM}	6	V	
Peak gate reverse voltage	V_{RGM}	6	V	
Peak gate forward current	I _{FGM}	0.3	Α	
Junction temperature	Tj	- 40 to +125	°C	
Storage temperature	Tstg	- 40 to +125	°C	
Mass	_	0.23	g	Typical value

Electrical Characteristics

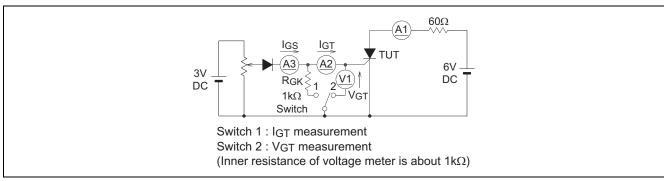
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak reverse current	I _{RRM}	_	_	0.1	mA	Tj = 125°C, V _{RRM} applied
Repetitive peak off-state current	I _{DRM}	_	_	0.1	mA	Tj = 125°C, V _{DRM} applied
						$R_{GK} = 1 k\Omega$
On-state voltage	V_{TM}	_	_	1.8	V	Tj = 25°C, I _{TM} = 4 A
						instantaneous value
Gate trigger voltage	V_{GT}	_	_	0.8	V	$Tj = 25^{\circ}C, V_D = 6 V, I_T = 0.1 A^{Note2}$
Gate non-trigger voltage	V_{GD}	0.2	_	_	V	$Tj = 125^{\circ}C, V_D = 1/2 V_{DRM}$
						$R_{GK} = 1 k\Omega$
Gate trigger current	I _{GT}	1 Note2	_	100 Note2	μ A	$Tj = 25^{\circ}C, V_D = 6 V, I_T = 0.1 A^{Note2}$
Holding current	I _H	_	_	3	mA	$Tj = 25$ °C, $V_D = 12$ V, $R_{GK} = 1$ kΩ
Thermal resistance	R _{th(j-a)}	_	_	180	°C/W	Junction to ambient

Notes: 2. If special values of I_{GT} are required, choose item D or E from those listed in the table below if possible.

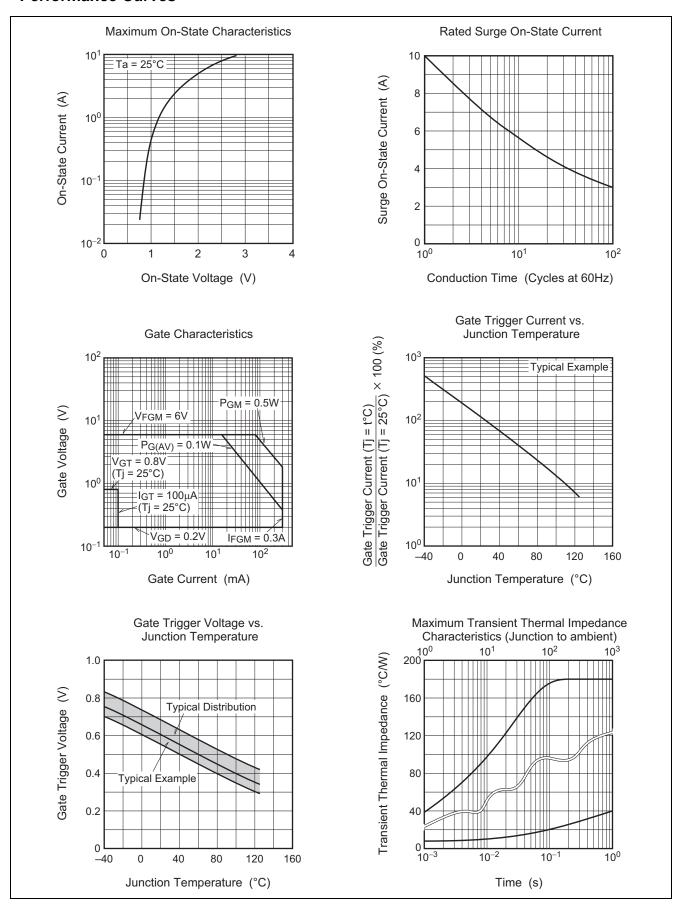
Item	D	E
I _{GT} (μA)	1 to 50	20 to 100

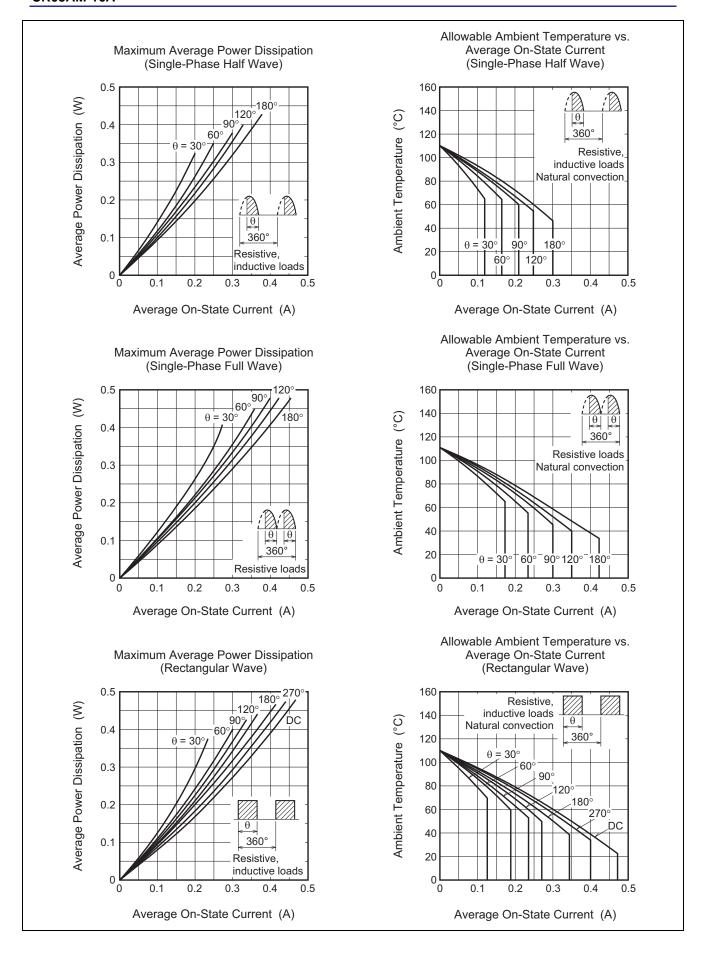
The above values do not include the current flowing through the 1 k Ω resistance between the gate and cathode.

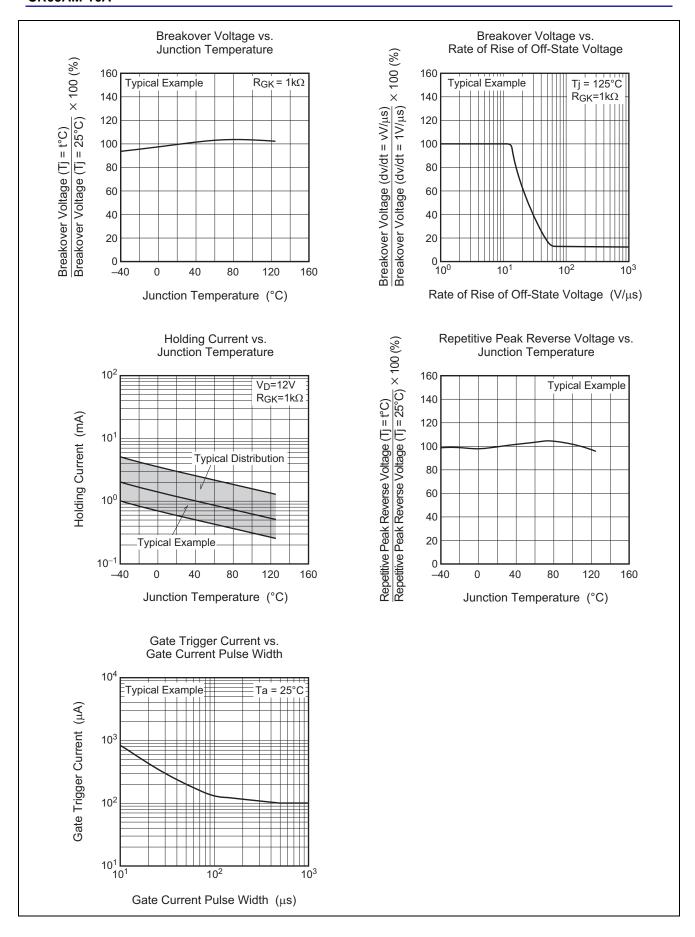
Notes: 3. Igt, Vgt measurement circuit.



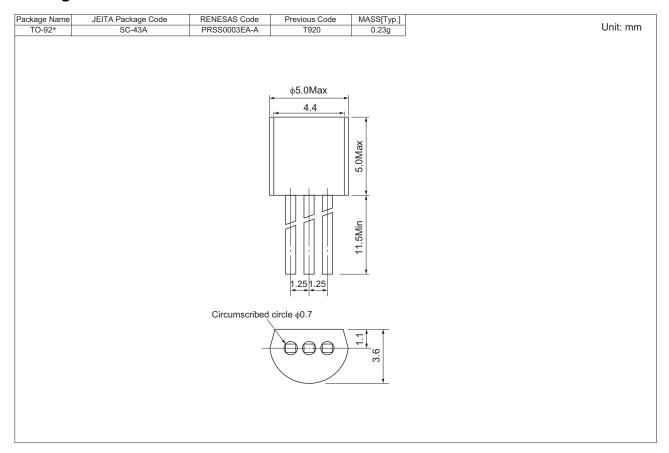
Performance Curves







Package dimensions



Ordering Information

Orderable Part Number	Packing	Quantity	Remark
CR05AM-16A#B00	Bag	500 pcs.	Straight type
CR05AM-16A-A6#B00	Bag	500 pcs.	A6 Lead form
CR05AM-16A-TB#B00	Embossed Tape	2000 pcs.	A8 Lead form, Taping direction "TB"

Note: Please confirm the specification about the shipping in detail.

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